

## Quad SPST CMOS Analog Switches

### FEATURES

- Low On-Resistance: 50  $\Omega$
- Low Leakage: 80 pA
- Low Power Consumption: 22 nW
- Fast Switching Action— $t_{ON}$ : 120 ns
- Low Charge Injection
- DG211/DG212 Upgrades
- TTL/CMOS Logic Compatible

### BENEFITS

- Low Signal Errors and Distortion
- Reduced Power Supply Requirements
- Faster Throughput
- Improved Reliability
- Reduced Pedestal Errors
- Simple Interfacing

### APPLICATIONS

- Audio Switching
- Battery Powered Systems
- Data Acquisition
- Sample-and-Hold Circuits
- Telecommunication Systems
- Automatic Test Equipment
- Single Supply Circuits
- Hard Disk Drives

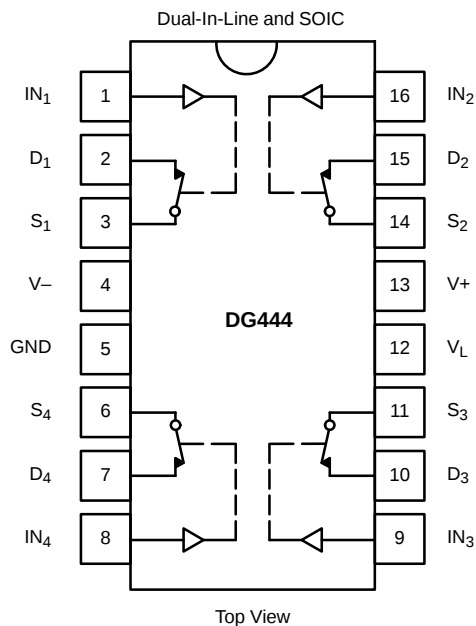
### DESCRIPTION

The DG444/DG445 monolithic quad analog switches are designed to provide high speed, low error switching of analog signals. The DG444 has a normally closed function. The DG445 has a normally open function. Combining low power (22 nW, typ) with high speed ( $t_{ON}$ : 120 ns, typ), the DG444/DG445 are ideally suited for upgrading DG211/212 sockets. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

To achieve high-voltage ratings and superior switching performance, the DG444/DG445 are built on Vishay Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply levels when off.

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE |       |       |
|-------------|-------|-------|
| Logic       | DG444 | DG445 |
| 0           | ON    | OFF   |
| 1           | OFF   | ON    |

Logic "0"  $\leq 0.8$  V  
Logic "1"  $\geq 2.4$  V

| ORDERING INFORMATION |                    |             |
|----------------------|--------------------|-------------|
| Temp Range           | Package            | Part Number |
| -40°C to 85°C        | 16-Pin Plastic DIP | DG444DJ     |
|                      |                    | DG445DJ     |
|                      | 16-Pin Narrow SOIC | DG444DY     |
|                      |                    | DG445DY     |



## ABSOLUTE MAXIMUM RATINGS

|                                                             |                                                            |
|-------------------------------------------------------------|------------------------------------------------------------|
| V+ to V−                                                    | 44 V                                                       |
| GND to V−                                                   | 25 V                                                       |
| V <sub>L</sub>                                              | (GND −0.3 V) to (V+) + 0.3 V                               |
| Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub> | (V−) −2 V to (V+) +2 V<br>or 30 mA, whichever occurs first |
| Continuous Current (Any Terminal)                           | 30 mA                                                      |
| Current, S or D (Pulsed 1 ms, 10% duty cycle)               | 100 mA                                                     |
| Storage Temperature                                         | −65 to 125°C                                               |

Power Dissipation (Package)<sup>b</sup>

|                                      |        |
|--------------------------------------|--------|
| 16-Pin Plastic DIP <sup>c</sup>      | 450 mW |
| 16-Pin Narrow Body SOIC <sup>d</sup> | 640 mW |

## Notes:

- Signals on S<sub>X</sub>, D<sub>X</sub>, or I<sub>NX</sub> exceeding V+ or V− will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC Board.
- Derate 6 mW/°C above 75°C
- Derate 8 mW/°C above 75°C

## SPECIFICATIONS FOR DUAL SUPPLIES

| Parameter                                   | Symbol              | Test Conditions<br>Unless Otherwise Specified<br>V <sub>+</sub> = 15 V, V <sub>−</sub> = −15 V<br>V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>e</sup> | Temp <sup>a</sup> | D Suffix<br>−40 to 85°C |                  |                  | Unit |     |
|---------------------------------------------|---------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-------------------------|------------------|------------------|------|-----|
|                                             |                     |                                                                                                                                                                     |                   | Min <sup>b</sup>        | Typ <sup>c</sup> | Max <sup>b</sup> |      |     |
| Analog Switch                               |                     |                                                                                                                                                                     |                   |                         |                  |                  |      |     |
| Analog Signal Range <sup>d</sup>            | V <sub>ANALOG</sub> |                                                                                                                                                                     | Full              | −15                     |                  | 15               | V    |     |
| Drain-Source On-Resistance                  | r <sub>DS(on)</sub> | I <sub>S</sub> = −10 mA, V <sub>D</sub> = ±8.5 V<br>V <sub>+</sub> = 13.5 V, V <sub>−</sub> = −13.5 V                                                               | Room<br>Full      |                         | 50               | 85<br>100        | Ω    |     |
| Switch Off Leakage Current                  | I <sub>S(off)</sub> | V <sub>+</sub> = 16.5 V, V <sub>−</sub> = −16.5 V<br>V <sub>D</sub> = ±15.5 V, V <sub>S</sub> = ∓15.5 V                                                             | Room<br>Full      | −0.5<br>−5              | ±0.01            | 0.5<br>5         | nA   |     |
|                                             | I <sub>D(off)</sub> |                                                                                                                                                                     | Room<br>Full      | −0.5<br>−5              | ±0.01            | 0.5<br>5         |      |     |
| Channel On Leakage Current                  | I <sub>D(on)</sub>  | V <sub>+</sub> = 16.5 V, V <sub>−</sub> = −16.5 V<br>V <sub>S</sub> = V <sub>D</sub> = ±15.5 V                                                                      | Room<br>Full      | −0.5<br>−10             | ±0.08            | 0.5<br>10        |      |     |
| Digital Control                             |                     |                                                                                                                                                                     |                   |                         |                  |                  |      |     |
| Input Current V <sub>IN</sub> Low           | I <sub>IL</sub>     | V <sub>IN</sub> under test = 0.8 V<br>All Other = 2.4 V                                                                                                             | Full              | −500                    | −0.01            | 500              | nA   |     |
| Input Current V <sub>IN</sub> High          | I <sub>IH</sub>     | V <sub>IN</sub> under test = 2.4 V<br>All Other = 0.8 V                                                                                                             | Full              | −500                    | 0.01             | 500              |      |     |
| Dynamic Characteristics                     |                     |                                                                                                                                                                     |                   |                         |                  |                  |      |     |
| Turn-On Time                                | t <sub>ON</sub>     | R <sub>L</sub> = 1 kΩ, C <sub>L</sub> = 35 pF<br>V <sub>S</sub> = ±10 V, See Figure 2                                                                               | Room              |                         | 120              | 250              | ns   |     |
| Turn-Off Time                               | t <sub>OFF</sub>    |                                                                                                                                                                     | DG444             | Room                    |                  | 110              |      | 140 |
|                                             |                     |                                                                                                                                                                     | DG445             | Room                    |                  | 160              |      | 210 |
| Charge Injection <sup>e</sup>               | Q                   | C <sub>L</sub> = 1 nF, V <sub>S</sub> = 0 V<br>V <sub>gen</sub> = 0 V, R <sub>gen</sub> = 0 Ω                                                                       | Room              |                         | −1               |                  | pC   |     |
| Off Isolation <sup>e</sup>                  | OIRR                | R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 5 pF, f = 1 MHz                                                                                                             | Room              |                         | 60               |                  | dB   |     |
| Crosstalk (Channel-to-Channel) <sup>d</sup> | X <sub>TALK</sub>   |                                                                                                                                                                     | Room              |                         | 100              |                  |      |     |
| Source Off Capacitance                      | C <sub>S(off)</sub> | f = 1 MHz                                                                                                                                                           | Room              |                         | 4                |                  | pF   |     |
| Drain Off Capacitance                       | C <sub>D(off)</sub> |                                                                                                                                                                     | Room              |                         | 4                |                  |      |     |
| Channel On Capacitance                      | C <sub>D(on)</sub>  | V <sub>ANALOG</sub> = 0 V                                                                                                                                           | Room              |                         | 16               |                  |      |     |
| Power Supplies                              |                     |                                                                                                                                                                     |                   |                         |                  |                  |      |     |
| Positive Supply Current                     | I <sub>+</sub>      | V <sub>+</sub> = 16.5 V, V <sub>−</sub> = −16.5 V<br>V <sub>IN</sub> = 0 or 5 V                                                                                     | Room<br>Full      |                         | 0.001            | 1<br>5           | μA   |     |
| Negative Supply Current                     | I <sub>−</sub>      |                                                                                                                                                                     | Room<br>Full      | −1<br>−5                | −0.0001          |                  |      |     |
| Logic Supply Current                        | I <sub>L</sub>      |                                                                                                                                                                     | Room<br>Full      |                         | 0.001            | 1<br>5           |      |     |
| Ground Current                              | I <sub>GND</sub>    |                                                                                                                                                                     | Room<br>Full      | −1<br>−5                | −0.001           |                  |      |     |

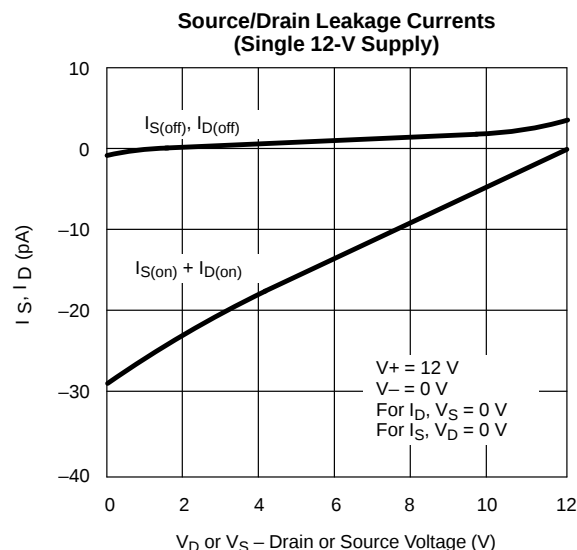
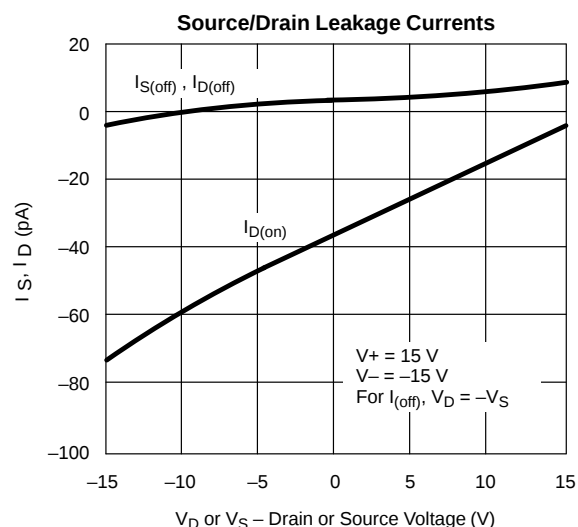
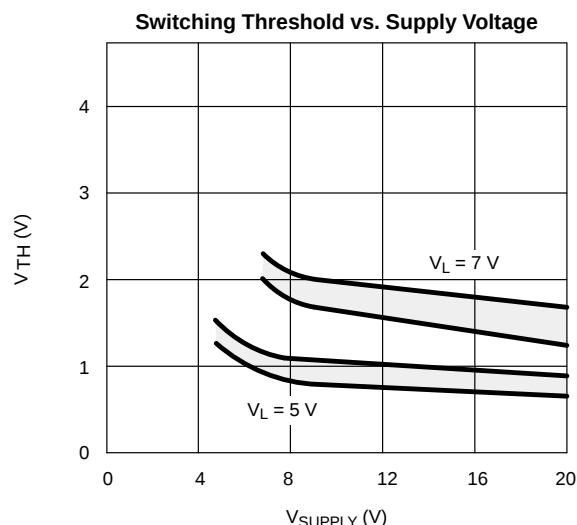
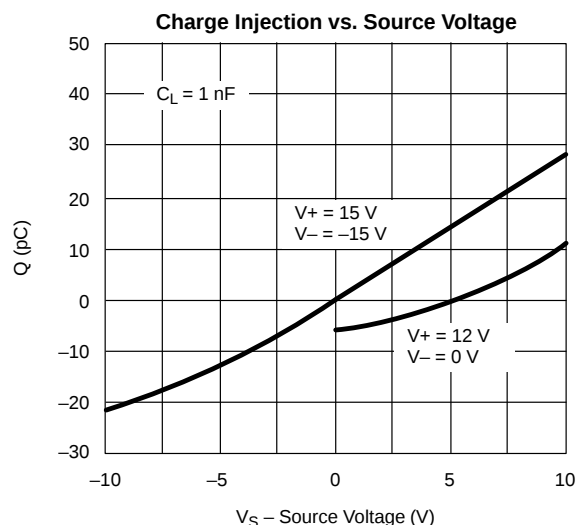
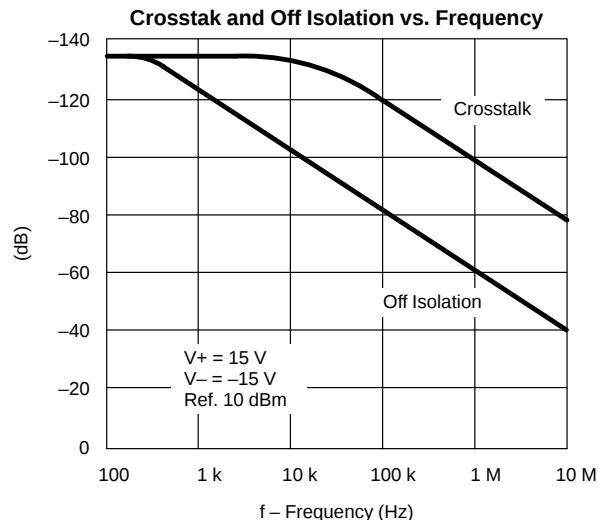
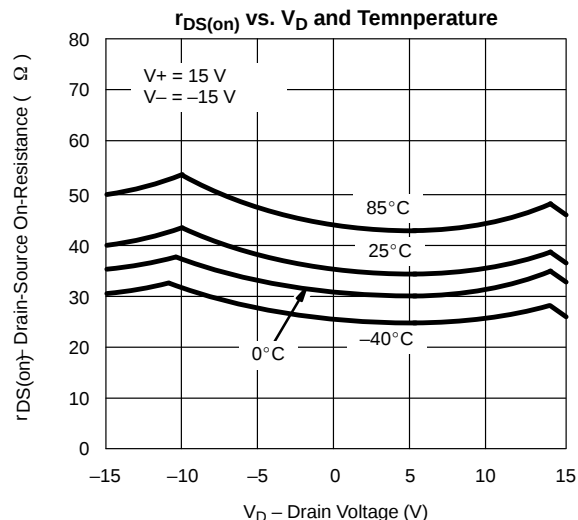


| SPECIFICATIONS FOR UNIPOLAR SUPPLIES    |         |                                                                                                                       |                   |                         |                  |                  |      |
|-----------------------------------------|---------|-----------------------------------------------------------------------------------------------------------------------|-------------------|-------------------------|------------------|------------------|------|
| Parameter                               | Symbol  | Test Conditions<br>Unless Otherwise Specified<br><br>V+ = 12 V, V− = 0 V<br>VL = 5 V, VIN = 2.4 V, 0.8 V <sup>e</sup> | Temp <sup>a</sup> | D Suffix<br>−40 to 85°C |                  |                  | Unit |
|                                         |         |                                                                                                                       |                   | Min <sup>b</sup>        | Typ <sup>c</sup> | Max <sup>b</sup> |      |
| Analog Switch                           |         |                                                                                                                       |                   |                         |                  |                  |      |
| Analog Signal Range <sup>d</sup>        | VANALOG |                                                                                                                       | Full              | 0                       |                  | 12               | V    |
| Drain-Source On-Resistance <sup>d</sup> | rDS(on) | IS = −10 mA, VD = 3 V, 8 V<br>V+ = 10.8 V, VL = 5.25 V                                                                | Room<br>Full      |                         | 100              | 160<br>200       | Ω    |
| Dynamic Characteristics                 |         |                                                                                                                       |                   |                         |                  |                  |      |
| Turn-On Time                            | tON     | RL = 1 kΩ, CL = 35 pF, VS = 8 V<br>See Figure 2                                                                       | Room              |                         | 300              | 450              | ns   |
| Turn-Off Time                           | tOFF    |                                                                                                                       | Room              |                         | 60               | 200              |      |
| Charge Injection                        | Q       | CL = 1 nF, Vgen = 6 V, Rgen = 0 Ω                                                                                     | Room              |                         | 2                |                  | pC   |
| Power Supplies                          |         |                                                                                                                       |                   |                         |                  |                  |      |
| Positive Supply Current                 | I+      | V+ = 13.2 V, VIN = 0 or 5 V                                                                                           | Room<br>Full      |                         | 0.001            | 1<br>5           | μA   |
| Negative Supply Current                 | I−      | VIN = 0 or 5 V                                                                                                        | Room<br>Full      | −1<br>−5                | −0.0001          |                  |      |
| Logic Supply Current                    | IL      | VL = 5.25 V, VIN = 0 or 5 V                                                                                           | Room<br>Full      |                         | 0.001            | 1<br>5           |      |
| Ground Current                          | IGND    | VIN = 0 or 5 V                                                                                                        | Room<br>Full      | −1<br>−5                | −0.001           |                  |      |

Notes:

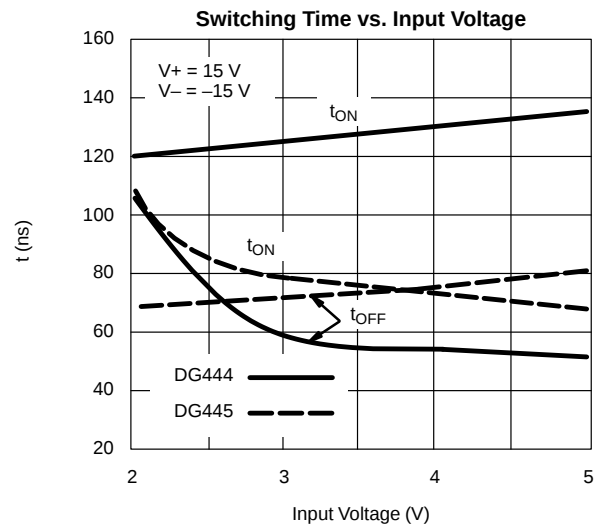
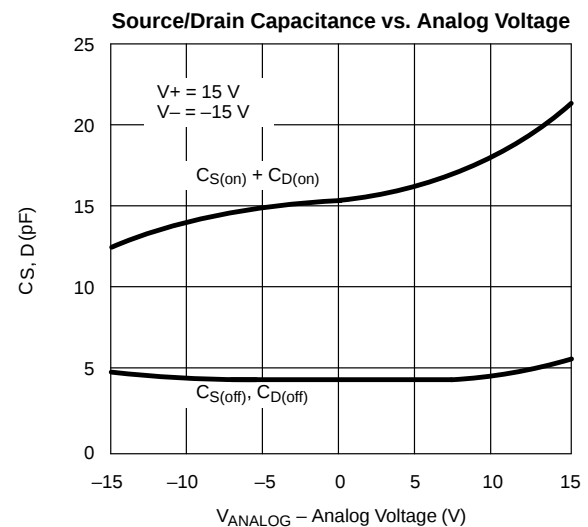
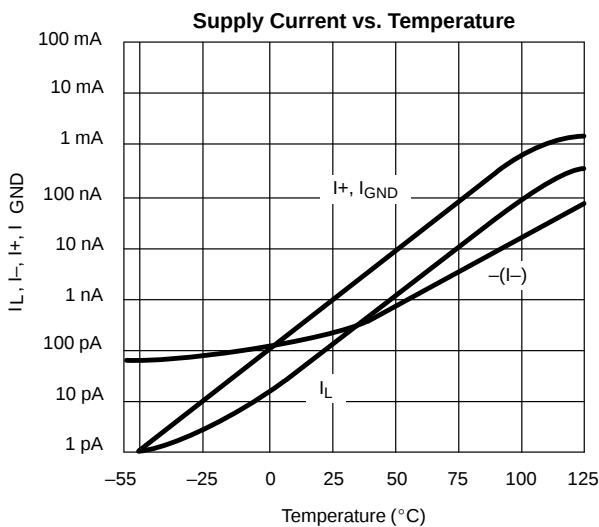
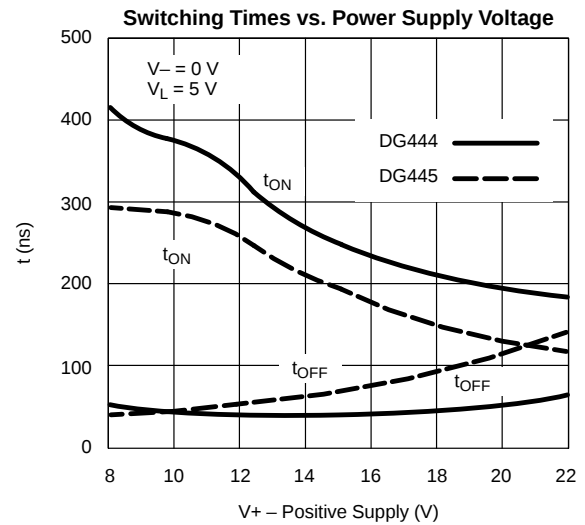
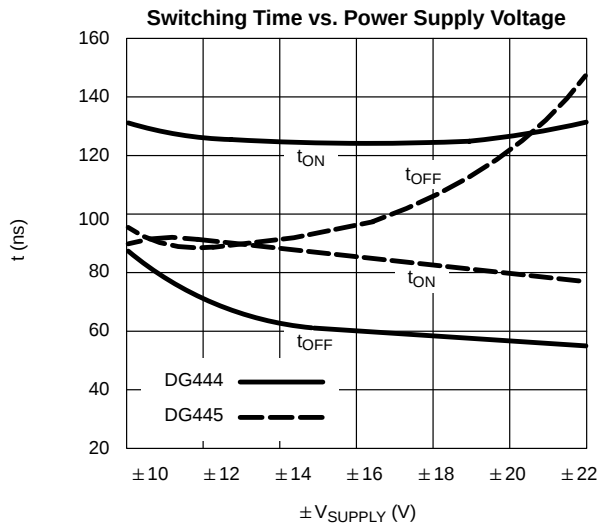
- Room = 25°C, Full = as determined by the operating temperature suffix.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**





**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**



**SCHEMATIC DIAGRAM (TYPICAL CHANNEL)**

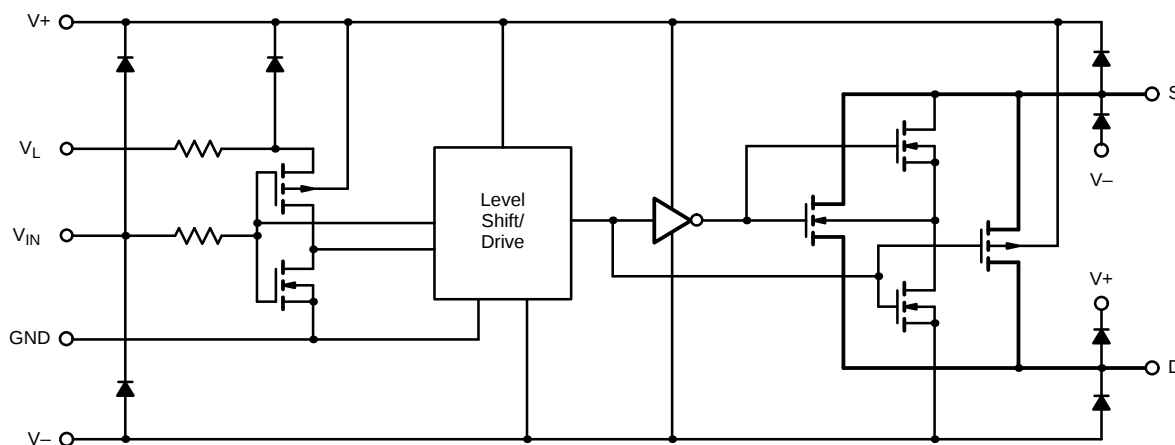
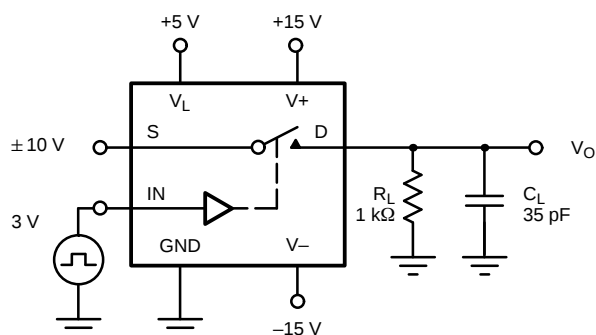
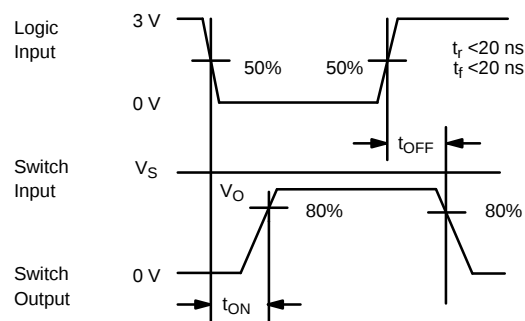


FIGURE 1.

**TEST CIRCUITS**



$C_L$  (includes fixture and stray capacitance)



Note: Logic input waveform is inverted for DG445.

FIGURE 2. Switching Time

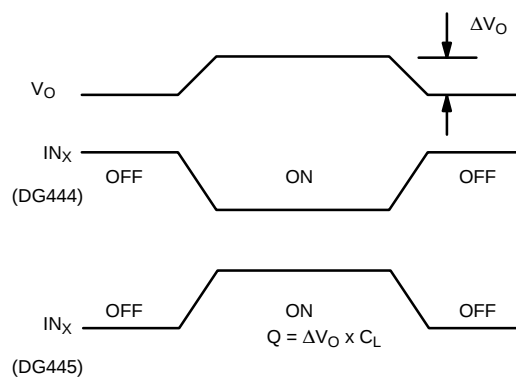
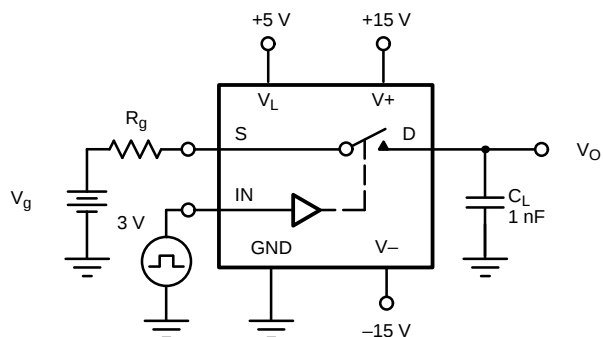
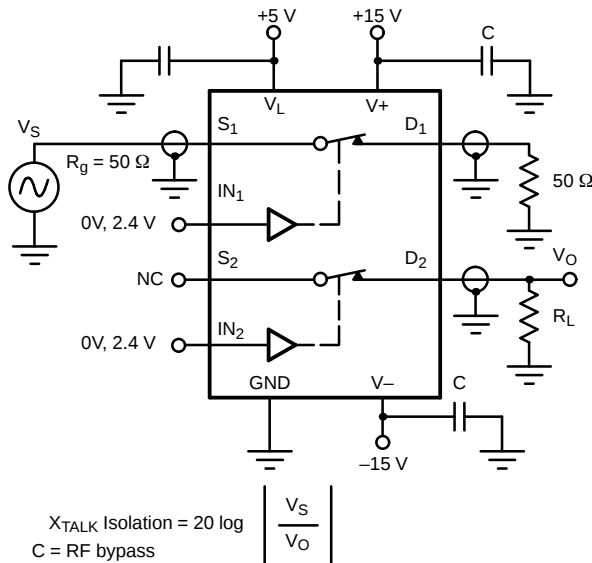


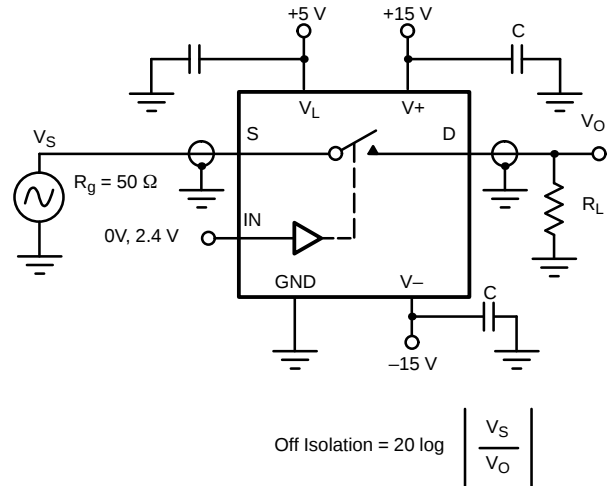
FIGURE 3. Charge Injection

## TEST CIRCUITS

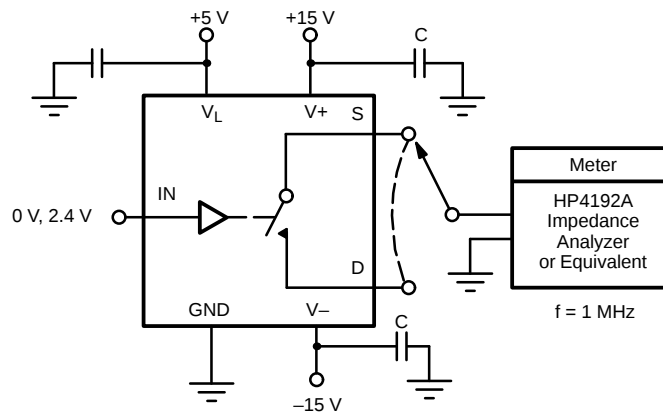
C = 1 mF tantalum in parallel with 0.01 mF ceramic



**FIGURE 4.** Crosstalk

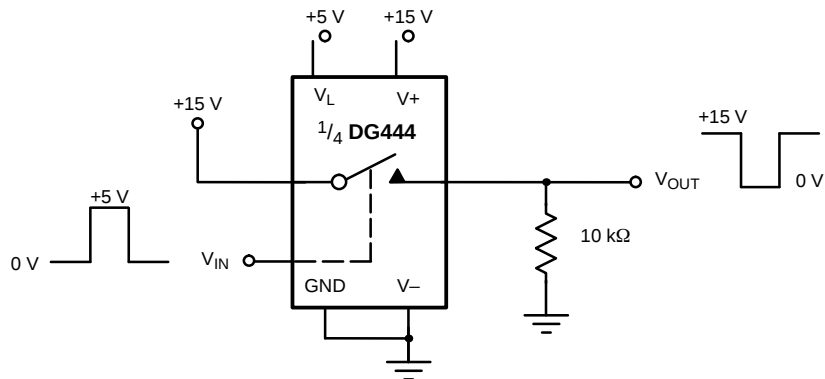


**FIGURE 5.** Off Isolation



**FIGURE 6.** Source/Drain Capacitances

## APPLICATIONS



**FIGURE 7.** Level Shifter

APPLICATIONS

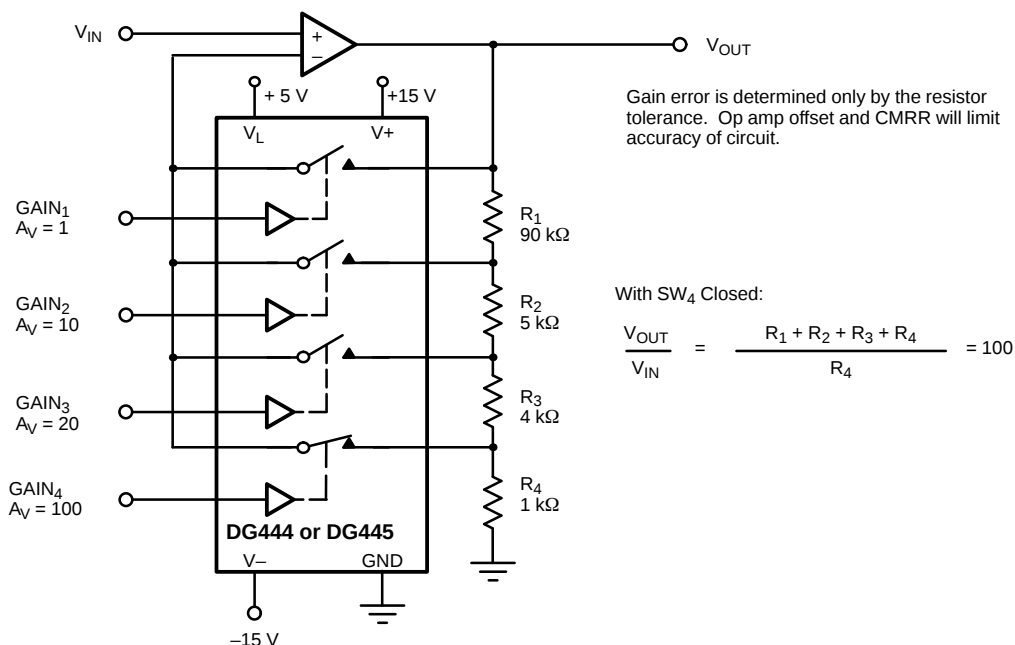


FIGURE 8. Precision-Weighted Resistor Programmable-Gain Amplifier

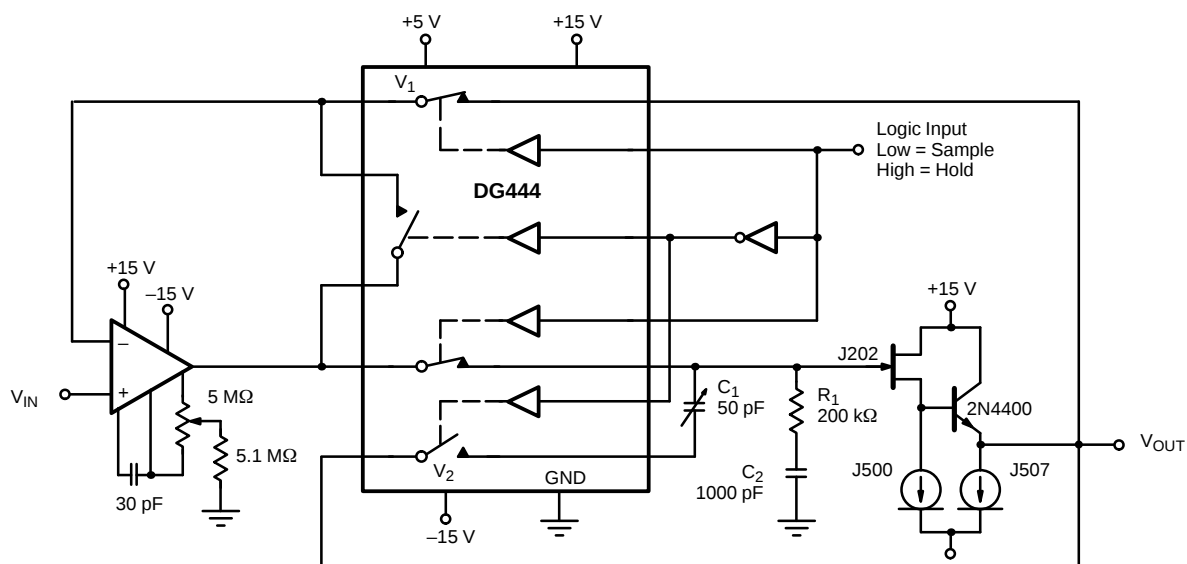


FIGURE 9. Precision Sample-and-Hold